



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Toshiya UEMURA

Serial No.: 10/694,811

Group Art Unit: 2812

Filed: October 20, 2003

Examiner: Mulpuri, Savitri

For: III GROUP NITRIDE SYSTEM COMPOUND SEMICONDUCTOR LIGHT
EMITTING ELEMENT AND METHOD OF MAKING SAME

Honorable Commissioner of Patents
Alexandria, Virginia 22313-1450

PAPER

Sir:

Further to an Information Disclosure Statement (IDS) filed January 23, 2004, submitted herewith is an additional form PTO-1449 which includes publication information of the Kazuyuki Tadatomo, et al., reference filed with the above-mentioned IDS. For the Examiner's convenience, a clearer copy of the reference which includes publication information is attached.

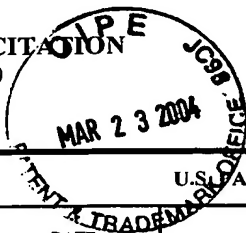
Respectfully Submitted,

Sean M. McGinn
Reg. No. 34,386

Date: 3/23/04

McGinn & Gibb, PLLC
Intellectual Property Law
8321 Old Courthouse Road, Suite 200
Vienna, Virginia 22182-3817
(703) 761-4100
Customer No. 21254

INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)



Docket Number (Optional) PTGF-03081		Application Number 10/694,811
Applicant(s) Toshiya UEMURA		
Filing Date October 20, 2003	Group Art Unit 2812	

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Kazuyuki Tadatomo, et al., "High Output Power InGaN Ultraviolet Light-Emitting Diodes Fabricated on Patterned Substrates Using Metalorganic Vapor Phase Epitaxy", Jpn. J. Appl. Phys. Vol. 40 (2001), pp. L583-L585, Part 2, No. 6B, June 15, 2001

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.